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TC7SG32FE

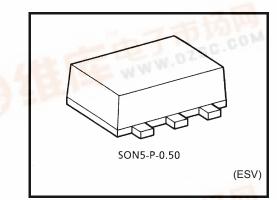
TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic



2 Input OR Gate

Features

- High-level output current: $I_{OH}/I_{OL} = \pm 8 \text{ mA} (\text{min})$ at V_{CC} = 3.0 V
- High-speed operation: t_{pd} = 2.4 ns (typ.)
 - at V_{CC} = 3.3 V,15pF Operating voltage range: V_{CC} = 0.9~3.6 V
- 5.5-V tolerant inputs.
- 3.6-V power down protection output.



Weight: 0.003 g (typ.) NWW.DZSC.COM

Marking

Pin Assignment (top view)



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Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Value	Unit		
Power supply voltage	V _{CC}	-0.5~4.6	V		
DC input voltage	VIN	-0.5~7.0	V		
	Vaur	−0.5~ 4.6 (Note 1)	v		
Power supply voltage DC input voltage DC output voltage Input diode current Output diode current DC output current DC V _{CC} /ground current Power dissipation	Vout	-0.5~ V _{CC} + 0.5 (Note 2)	V		
Input diode current	I _{IK}	-20	mA		
Output diode current	I _{OK}	-20 (Note 3)	mA		
DC output current	IOUT	±25	mA		
DC V _{CC} /ground current	Icc	±50	mA		
Power dissipation	PD	150	mW		
Storage temperature	T _{stg}	-65~1 <mark>50</mark>	°C		

Note:

ote 3:

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

1

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

$V_{CC} = 0V$ Note 1:

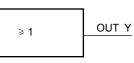
Note 2 D FHigh or Low State. IOUT abusolute maximum rating must be observed. VOUT < GND

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IEC Logic Symbol

IN А — IN В —



А	В	Y
L	L	L
L	Н	Н
Н	L	Н
Н	Н	Н

Truth Table

Operating Ranges

Characteristics	Symbol	Value	Unit	
Power supply voltage	V _{CC}	0.9~3.6	V	
Input voltage	V _{IN}	0~5.5	V	
Output voltage	Varia	0~3.6 (Note 4)	V	
	Vout	0~V _{CC} (Note 5)	v	
Output Current		±8.0 (Note 6)		
		±4.0 (Note 7)		
	1 /1	±3.0 (Note 8)	~ ^	
	I _{OH} /I _{OL}	±1.7 (Note 9)	mA	
		±0.3 (Note 10)		
		±0.02 (Note 11)		
Operating temperature	T _{opr}	-40~85	°C	
Input rise and fall time	dt/dV	0~10 (Note 12)	ns/V	

Note 4: $V_{CC} = 0V$

Note 5: High or Low state.

- Note 6: $V_{CC} = 3.0 \sim 3.6 \text{ V}$
- Note 7: V_{CC} = 2.3~2.7 V
- Note 8: $V_{CC} = 1.65 \sim 1.95 \text{ V}$
- Note 9: V_{CC} = 1.4~1.6 V
- Note 10: $V_{CC} = 1.1 \sim 1.3 \text{ V}$
- Note 11: $V_{CC} = 0.9 V$
- Note 12: $V_{IN} = 0.8 \sim 2.0 \text{ V}, V_{CC} = 3.0 \text{ V}$

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DC Electrical Characteristics

Characteristics Symbol Test Condition		Tost Condition			Ta = 25°C			Ta = -40~85°C		Unit
		Condition	V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit	
				0.9	V _{CC}	_	_	V _{CC}	_	
				1.1~1.3	V _{CC} × 0.7		_	V _{CC} × 0.7	_	V
High-level VIH input voltage	VIH			1.4~1.6	V _{CC} × 0.65	_	_	V _{CC} × 0.65	_	
				1.65~1.95	V _{CC} × 0.65	_	_	V _{CC} × 0.65		
				2.3~2.7	1.7	_	_	1.7	_	
				3.0~3.6	2.0	_	_	2.0	_	
				0.9	_	_	GND		GND	
				1.1~1.3	_		V _{CC} × 0.3	_	V _{CC} × 0.3	
Low-level	VIL		_	1.4~1.6			$\begin{array}{c} V_{CC} \\ \times \ 0.35 \end{array}$	_	$\begin{array}{c} V_{CC} \\ \times \ 0.35 \end{array}$	
input voltage				1.65~1.95	_	_	V _{CC} × 0.35	_	V _{CC} × 0.35	
				2.3~2.7	_	_	0.7		0.7	
				3.0~3.6	—	_	0.8		0.8	
		VIN = VIH or VIL	I _{OH} =-0.02 mA	0.9	0.75	_	_	0.75	_	- V
	Vон		I _{OH} = -0.3 mA	1.1~1.3	V _{CC} × 0.75	_	_	V _{CC} × 0.75	_	
High-level output voltage			I _{OH} = -1.7 mA	1.4~1.6	V _{CC} × 0.75		_	V _{CC} × 0.75	_	
	-		I _{OH} = -3.0 mA	1.65~ 1.95	V _{CC} -0.45	_	_	V _{CC} -0.45	_	
			I _{OH} = -4.0 mA	2.3~2.7	2.0			2.0	_	
			I _{OH} = -8.0 mA	3.0~3.6	2.48			2.48	_	
		$V_{IN} = V_{IL}$	I _{OL} = 0.02 mA	0.9	—		0.1		0.1	V
Low-level output voltage	V _{OL}		I _{OL} = 0.3 mA	1.1~1.3	_		$\begin{array}{c} V_{CC} \\ \times \ 0.25 \end{array}$	_	V _{CC} × 0.25	
			I _{OL} = 1.7 mA	1.4~1.6			$\begin{array}{c} V_{CC} \\ \times \ 0.25 \end{array}$	_	V _{CC} × 0.25	
			I _{OL} = 3.0 mA	1.65~ 1.95	_	_	0.45	_	0.45	
			I _{OL} = 4.0 mA	2.3~2.7			0.4		0.4	
			I _{OL} = 8.0 mA	3.0~3.6			0.4		0.4	
Input leakage current	I _{IN}	V _{IN} = 0~5.5V		0~3.6	_		±0.1	_	±1.0	μA
Power off leakage current	IOFF	V _{IN} = 0~5.5V V _{OUT} = 0~3.6V		0	_		1.0	_	10.0	μA
Quiescent supply current	ICC	VIN = VCC or GND		3.6	_		1.0		10.0	μΑ

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AC Electrical Characteristics (input $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40~85°C		L Incit
Characteristics	Symbol	Test Condition	C _{L (} pF)	Min	Тур.	Max	Min	Max	Unit
		$C_L = 10 \text{ pF},$ $R_L = 1 \text{ M}\Omega$	0.9	_	17.0	_	_	_	
			1.1~1.3	_	8.8	18.4	1.0	34.2	
			1.4~1.6	_	5.0	8.5	1.0	10.0	
			1.65~ 1.95	_	3.8	6.2	1.0	6.7	
			2.3~2.7	_	2.7	3.9	1.0	4.4	
			3.0~3.6	_	2.1	3.1	1.0	3.7	
			0.9	_	20.7	_	_	_	
Propagation delay time	tрLH tpHL	$C_L = 15 \text{ pF},$ $R_L = 1 \text{ M}\Omega$	1.1~1.3	_	10.6	21.5	1.0	37.2	ns
			1.4~1.6	_	5.9	9.3	1.0	11.2	
			1.65~ 1.95	_	4.5	6.9	1.0	7.1	
			2.3~2.7	_	3.0	4.4	1.0	5.0	
			3.0~3.6	_	2.4	3.4	1.0	3.9	
		$C_L = 30 \text{ pF},$ $R_L = 1 \text{ M}\Omega$	0.9	_	29.6	_	_	_	
			1.1~1.3	_	14.8	29.6	1.0	56.0	
			1.4~1.6	_	8.0	13.1	1.0	15.9	
			1.65~ 1.95	_	6.0	9.2	1.0	9.6	
			2.3~2.7	_	3.9	5.7	1.0	6.1	
			3.0~3.6		3.0	4.4	1.0	4.8	
Input capacitance	C _{IN}		3.6		3			_	pF
Power dissipation capacitance	C _{PD}	(Note 13)	0.9~3.6	_	6	_	_		pF

Note 13: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

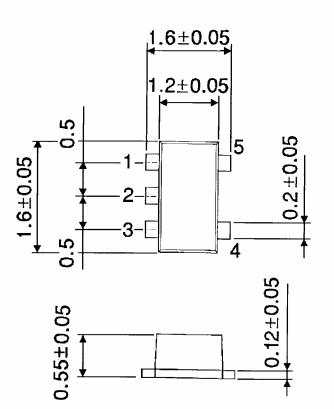
Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

TOSHIBA

Package Dimensions

SON5-P-0.50



Weight: 0.003 g (typ.)

TC7SG32FE

TOSHIBA

RESTRICTIONS ON PRODUCT USE

Handbook" etc.

20070701-EN GENERAL

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